

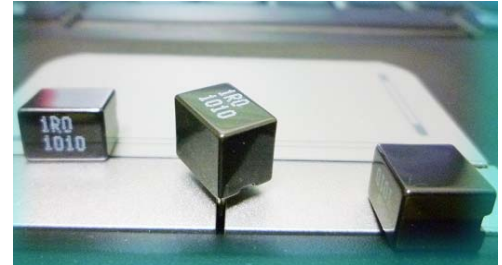


QS100709P Series

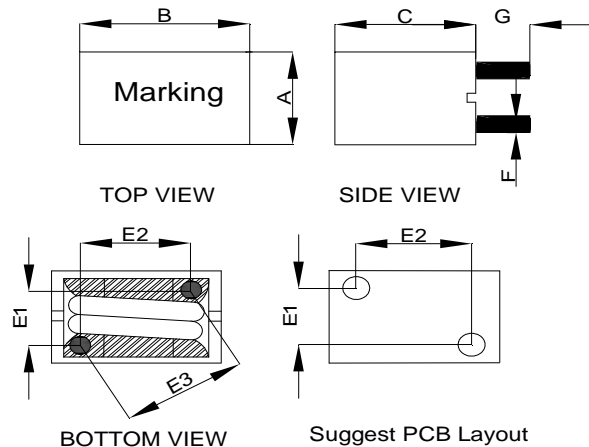


1. Features:

- Inductor with lower core loss for high frequency application.
- Inductance Range:0.22uH to 4.70uH. Custom values are welcomed.
- High current output chokes, up to 46 Amp.
- Ideal for desktop computers,servers,workstations,VGA card ,High-End switches and routers,Voltage-regulator modules & High Density Board Design.
- Very low DC resistance and compact size,high performance,low cost.
- Operating Temperature Range -40°C to + 125°C; RoHs & HF compliance



2. Mechanical Dimension(Unit:mm):



Type	QS100709P
A	7.5 (Max.)
B	10.5 (Max.)
C	8.9 (Max.)
E1	(R22~R80)3.9±0.5
	(1R0~2R0)4.4±0.5
	(2R2~4R7)4.6±1.0
E2	(R22~R80)6.1±0.5
	(1R0~2R0)6.6±0.5
	(2R2~4R7)6.8±1.0
E3	(R22~R80)7.2±0.5
	(1R0~2R0)8.0±0.5
	(2R2~4R7)8.2±1.0
F	See below table
G	3.5±0.5

3. Electrical Characteristic of QS100709P Series:

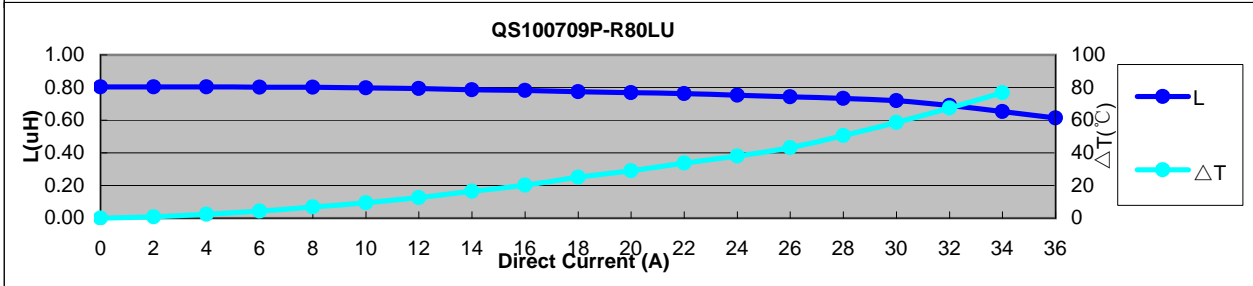
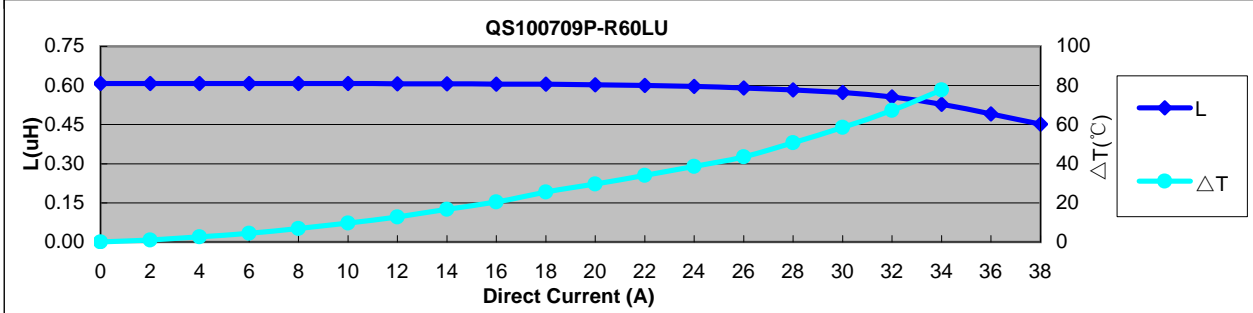
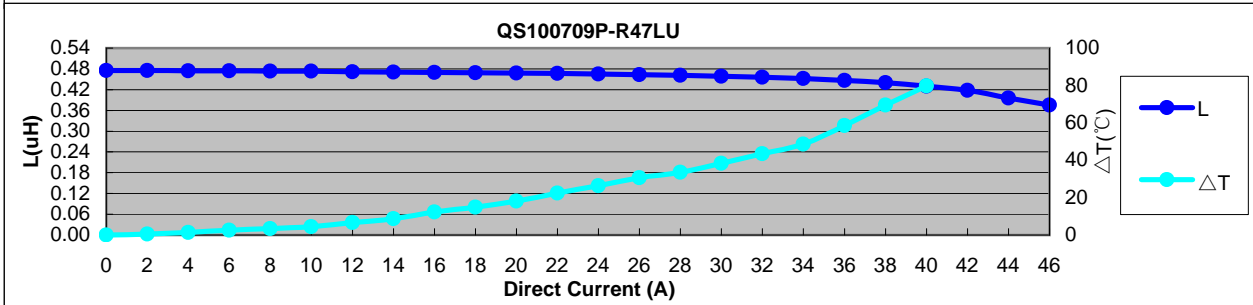
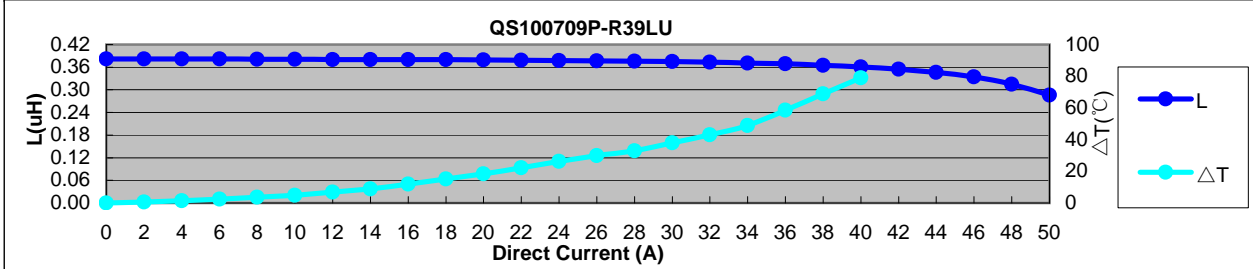
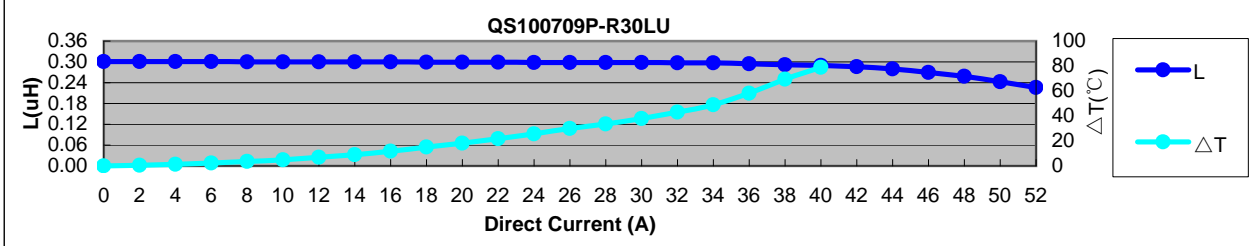
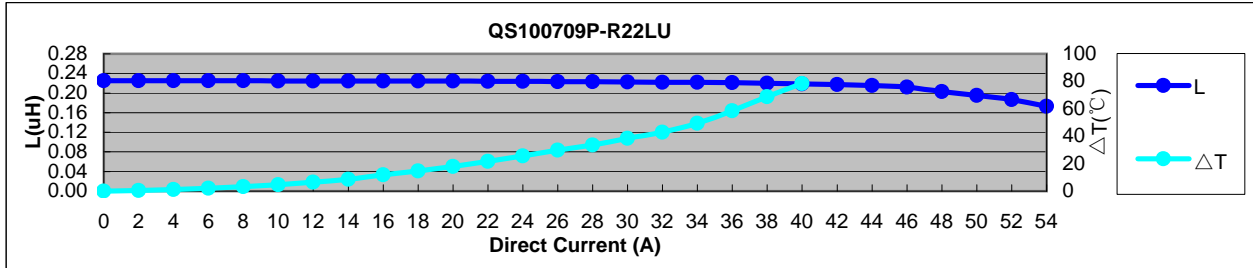
Part Number	OCL (uH) ±15%	DCR (mΩ) ±8%	Isat (A) @25°C	L@Isat (uH) Typ.	Irms (A) @25°C	L@Irms (uH) Typ.	Dimension F (mm)
QS100709P-R22LU	0.22	0.68	46.0	0.212	30.0	0.223	1.40
QS100709P-R30LU	0.30	0.68	44.0	0.279	30.0	0.298	1.40
QS100709P-R39LU	0.39	0.68	42.0	0.355	30.0	0.375	1.40
QS100709P-R47LU	0.47	0.68	40.0	0.430	30.0	0.459	1.40
QS100709P-R60LU	0.60	1.25	34.0	0.528	24.0	0.596	1.20
QS100709P-R80LU	0.80	1.25	32.0	0.691	24.0	0.752	1.20
QS100709P-1R0LU	1.00	2.60	26.0	0.860	18.0	0.965	0.90
QS100709P-1R2LU	1.20	2.60	24.0	1.060	18.0	1.240	0.90
QS100709P-1R5LU	1.50	3.90	22.0	1.260	15.0	1.450	0.80
QS100709P-2R0LU	2.00	3.90	20.0	1.770	15.0	1.930	0.80
QS100709P-2R2LU	2.20	7.90	18.0	1.860	10.0	2.184	0.65
QS100709P-2R5LU	2.50	7.90	15.0	2.150	10.0	2.462	0.65
QS100709P-3R0LU	3.00	10.80	13.0	2.620	7.0	3.027	0.55
QS100709P-3R5LU	3.50	10.80	12.0	2.960	7.0	3.536	0.55
QS100709P-4R0LU	4.00	14.00	10.0	3.480	6.0	3.960	0.50
QS100709P-4R7LU	4.70	14.00	9.0	4.180	6.0	4.636	0.50

Note:

- 1.OCL (Open Circuit Inductance) and L@ Irms and L @Isat are measured at: 100KHz, 1.0V @ 25°C.
- 2.Isat: DC current that causes inductance to drop by approximately 20% from OCL ;(Ta=25°C).
- 3.Irms: DC current that causes an approximate temperature rise (ΔT) of 40°C ;(Ta=25°C).
- 4.Inductance and Temperature rise Vs. DC bias curve,please see the next page to get more detail information.

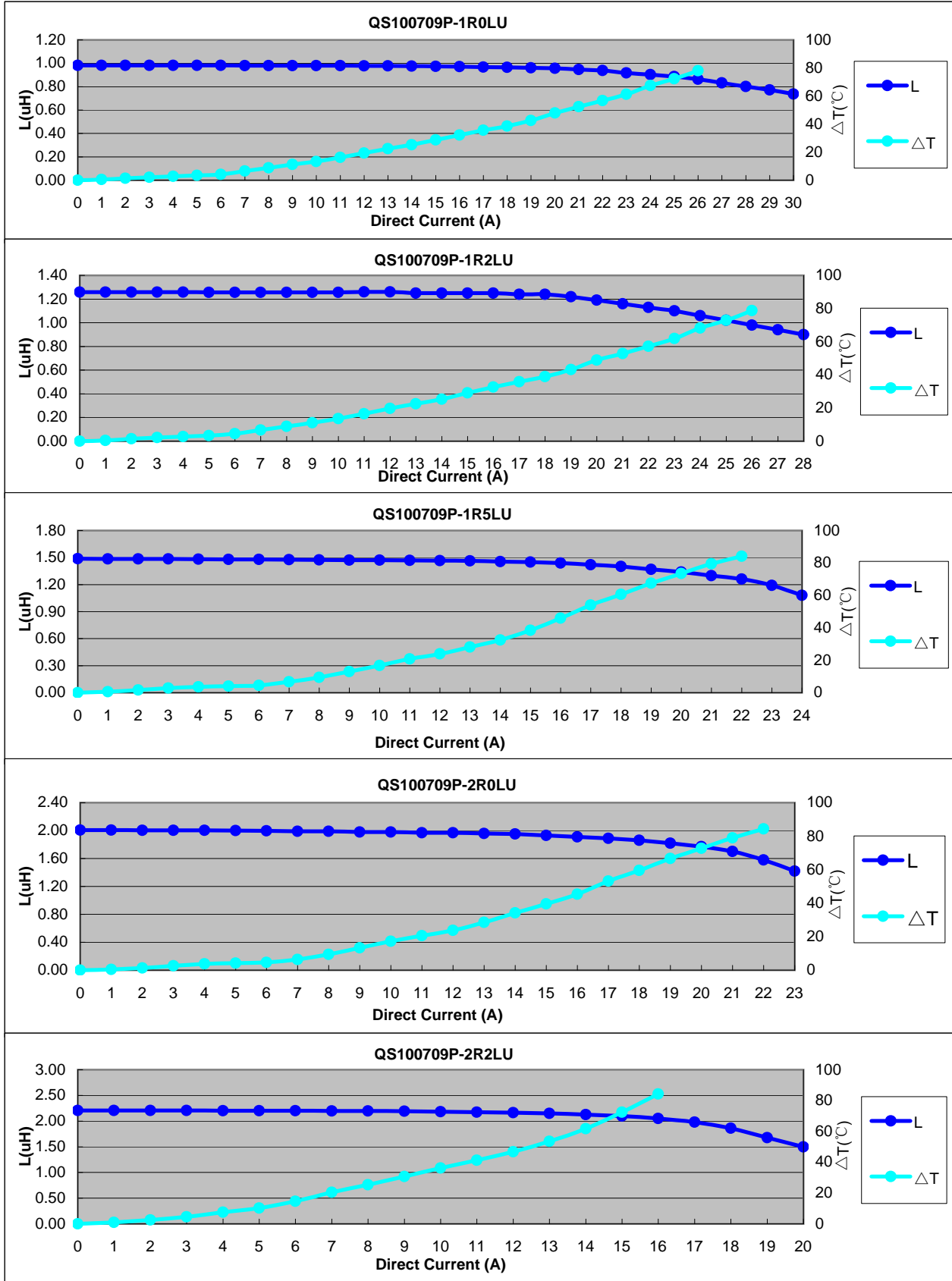


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